

Technical Data Data Sheet N0130, Rev. B

**MBR1545 SCHOTTKY RECTIFIER** 

#### **Applications:**

- Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection
- Center tap configuration

#### Features:

- 150 °C T<sub>J</sub> operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- This is a Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request



#### **Mechanical Dimensions (In mm)**





Symbol	D	imensions millimeters		
	Min. Typical		Max.	
Α	4.55	4.70	4.85	
A1	1.17	1.27	1.37	
A2	2.59	2.69	2.89	
b	0.71	0.81	0.96	
b1	1.27			
С	0.36	0.38	0.61	
D	14.64	14.94	15.24	
D1	8.55	8.07	8.85	
E	10.01	10.16	10.31	
E1	9.98	10.18	10.38	
e1		5.08		
H1	6.04	6.24	6.44	
L	13.00	13.86	14.08	
L1		3.80		
ΦΡ	3.74	3.84	4.04	
Q	2.54	2.74	2.94	
Θ1		5°		
Θ2		4°		
Θ3		4°		

### **TO-220AC**

- China Germany Korea Singapore United States •
- http://www.smc-diodes.com sales@ smc-diodes.com •

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## Marking Diagram:



Where XXXXX is YYWWL

MBR	= Device Type
15	= Forward Current (15A)
45	= Reverse Voltage (45V)
SSG	= SSG
ΥY	= Year
WW	= Week
L	= Lot Number

Cautions: Molding resin Epoxy resin UL:94V-0

## **Ordering Information:**

Device	Package	Shipping	
MBR1545	TO-220AC(Pb-Free)	50pcs/ tube	

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification.

## Maximum Ratings:

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>R</sub>	-	45	
Average Rectified Forward Current	I <sub>F (AV)</sub>	50% duty cycle @T <sub>c</sub> =123 °C, rectangular wave form	15	A
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	8.3 ms, half Sine pulse	240	A

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## **Electrical Characteristics:**

Characteristics	Symbol	Condition	Max.	Units
Forward Voltage Drop*	$V_{F1}$	@ 15 A, Pulse, T <sub>J</sub> = 25 °C	0.70	V
	V <sub>F2</sub>	@ 15 A, Pulse, T <sub>J</sub> = 125 °C	0.60	V
Reverse Current (per leg) *	I <sub>R1</sub>	$@V_R = rated V_R$	1.0	mA
		T <sub>C</sub> = 25 °C		
	I <sub>R2</sub>	$@V_{R} = rated V_{R}$	40	mA
		T <sub>C</sub> = 125 °C		
Junction Capacitance	CT	@V <sub>R</sub> = 5V, T <sub>C</sub> = 25 °C	800	pF
(per leg)		f <sub>SIG</sub> = 1MHz		
Typical Series Inductance	Ls	Measured lead to lead 5 mm from	8.0	nH
(per leg)		package body		
Voltage Rate of Change	dv/dt	-	10,000	V/µs

\* Pulse Width < 300µs, Duty Cycle <2%

## Thermal-Mechanical Specifications:

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +150	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical Thermal Resistance Junction to Case (per leg)	$R_{ ext{ heta}JC}$	DC operation	1.6	°C/W
Approximate Weight	wt	-	1.6	g
Case Style		TO-220AC		



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#### Fig.1-Typical Junction Capacitance

Fig.2-Typical Reverse Characteristics



Fig.3-Typical Instantaneous Forward Voltage Characteristics



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